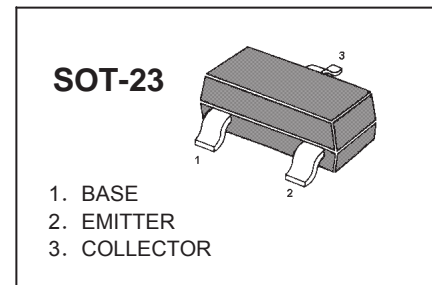


## BC818... TRANSISTOR (NPN)

### FEATURE

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC808 (PNP)



### MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
$V_{CB0}$	Collector-Base Voltage	30	V
$V_{CE0}$	Collector-Emitter Voltage	25	V
$V_{EB0}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	0.5	A
$P_C$	Collector Power Dissipation	0.3	W
$T_j$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^{\circ}\text{C}$

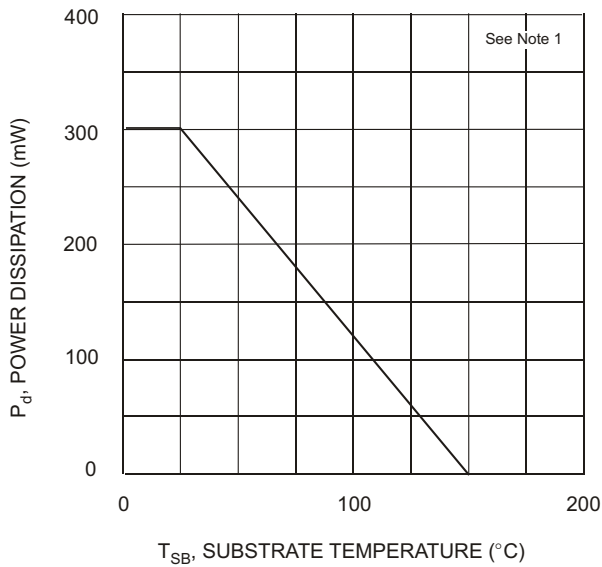
### ELECTRICAL CHARACTERISTICS ( $T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{CB0}$	$I_C=10\mu\text{A}$ , $I_E=0$	30			V
Collector-emitter breakdown voltage	$V_{CE0}$	$I_C=10\text{mA}$ , $I_B=0$	25			V
Emitter-base breakdown voltage	$V_{EB0}$	$I_E=1\mu\text{A}$ , $I_C=0$	5			V
Collector cut-off current	$I_{CB0}$	$V_{CB}=45\text{V}$ , $I_E=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EB0}$	$V_{EB}=4\text{V}$ , $I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}$	$V_{CE}=1\text{V}$ , $I_C=100\text{mA}$	100		600	
	$h_{FE(2)}$	$V_{CE}=1\text{V}$ , $I_C=500\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500\text{mA}$ , $I_B=50\text{mA}$			0.7	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=500\text{mA}$ , $I_B=50\text{mA}$			1.2	V
Base-emitter voltage	$V_{BE}$	$V_{CE}=1\text{V}$ , $I_C=500\text{mA}$			1.2	V
Collector capacitance	$C_{ob}$	$V_{CB}=10\text{V}$ , $f=1\text{MHz}$		10		pF
Transition frequency	$f_T$	$V_{CE}=5\text{V}$ , $I_C=10\text{mA}$ $f=100\text{MHz}$	100			MHz

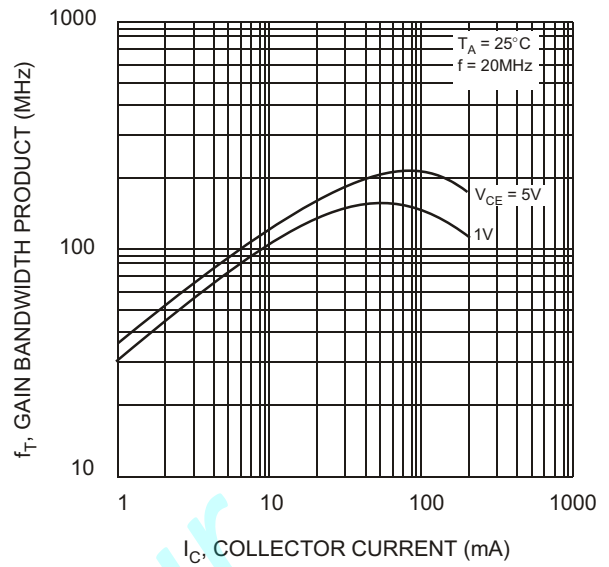
### CLASSIFICATION OF $h_{FE(1)}$

Rank	BC818-16	BC818-25	BC818-40
Range	100-250	160-400	250-600
Marking	6E	6F	6G

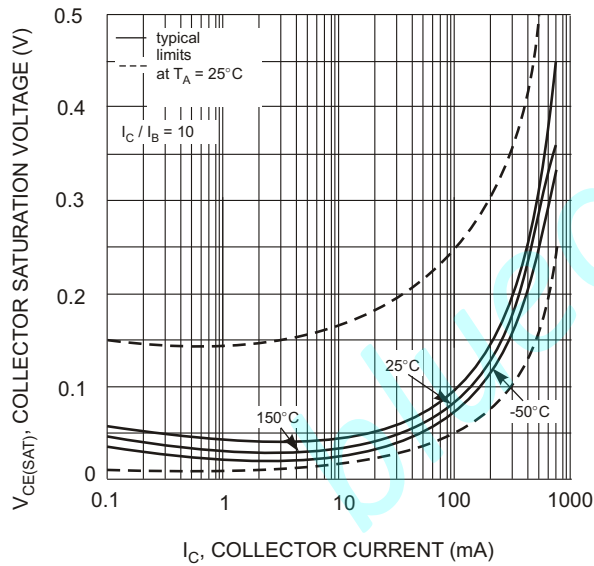
## Typical Characteristics



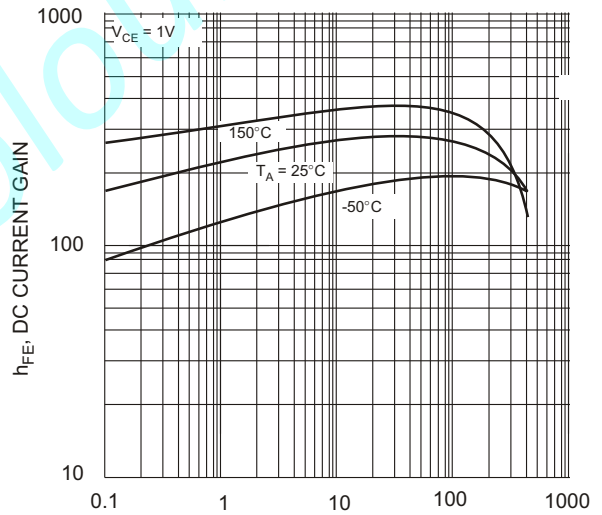
$T_{SB}$ , SUBSTRATE TEMPERATURE (°C)  
Fig. 1, Power Derating Curve



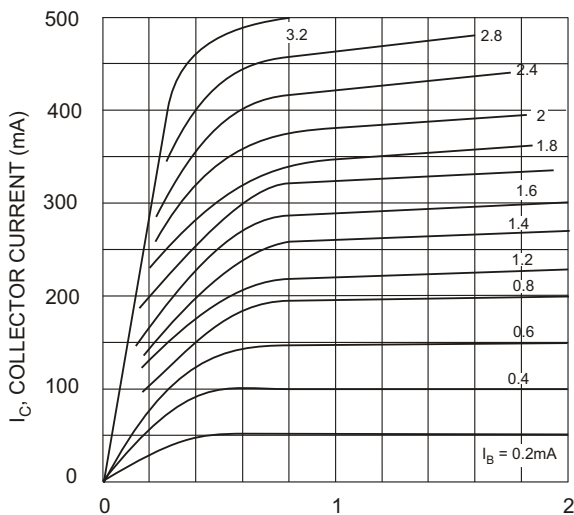
$I_C$ , COLLECTOR CURRENT (mA)  
Fig. 2, Gain-Bandwidth Product vs Collector Current



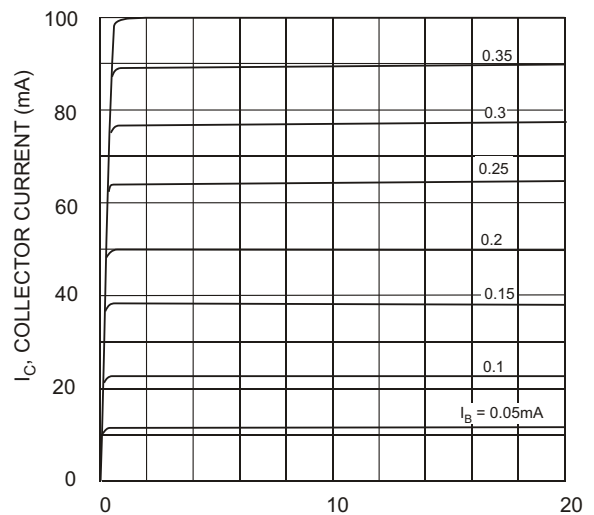
$I_C$ , COLLECTOR CURRENT (mA)  
Fig. 3, Collector Sat. Voltage vs Collector Current



$I_C$ , COLLECTOR CURRENT (mA)  
Fig. 4, DC Current Gain vs Collector Current



$V_{CE}$ , COLLECTOR-EMITTER VOLTAGE (V)  
Fig. 5, Typical Emitter-Collector Characteristics



$V_{CE}$ , COLLECTOR-EMITTER VOLTAGE (V)  
Fig. 6, Typical Emitter-Collector Characteristics

## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23

